

DSC60XX

Ultra-Small, Ultra-Low Power MEMS Oscillator

Features

- · Wide Frequency Range: 2 kHz to 80 MHz
- Ultra-Low Power Consumption: 1.3 mA/12 μA (Active/Stdby)
- Ultra-Small Footprints
 - 1.6 mm × 1.2 mm
 - 2.0 mm × 1.6 mm
 - $2.5 \text{ mm} \times 2.0 \text{ mm}$
 - $3.2 \text{ mm} \times 2.5 \text{ mm}$
- Frequency Select Input Supports 2 Predefined Frequencies
- · High Stability: ±25, ±50 ppm
- · Wide Temperature Range
 - Industrial: -40°C to 85°C
 - Ext. Commercial: -20° to 70°C
- · Excellent Shock & Vibration Immunity
 - Qualified to MIL-STD-883
- · High Reliability
 - 20x Better MTF Than Quartz Oscillators
- Supply Range of 1.71V to 3.63V
- Short Sample Lead Time: <2 weeks
- · Lead Free & RoHS Compliant

Applications

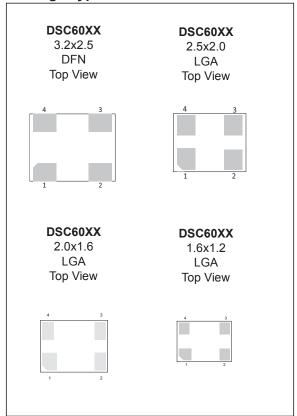
- Low Power/Portable Applications IoT, Embedded/Smart Devices
- Consumer Home Healthcare, Fitness Devices, Home Automation
- Automotive Rear View/Surround View Cameras, Infotainment System
- Industrial Building/Factory Automation, Surveillance Camera

General Description

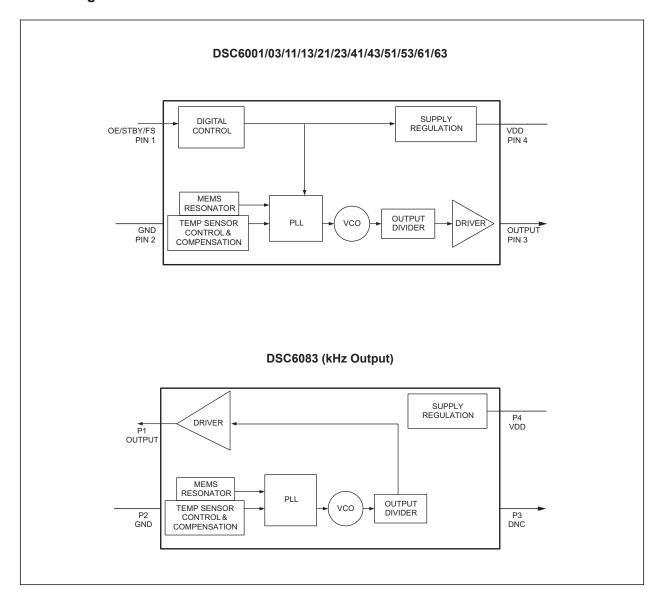
The DSC60xx family of MEMS oscillators combines industry-leading low-power consumption, ultra-small packages with exceptional frequency stability, and jitter performance over temperature. The single-output DSC60xx MEMS oscillators are excellent choices for use as clock references in small, battery-powered devices such as wearable and Internet of Things (IoT) devices in which small size, low power consumption, and long-term reliability are paramount. They also meet the stringent mechanical durability and reliability requirements within Automotive Electronics Council standard Q100 (AEC-Q100), so they are well suited for under-hood applications as well.

The DSC60xx family is available in ultra-small $1.6~\text{mm} \times 1.2~\text{mm}$ and $2.0~\text{mm} \times 1.6~\text{mm}$ packages. Other package sizes include: $2.5~\text{mm} \times 2.0~\text{mm}$ and $3.2~\text{mm} \times 2.5~\text{mm}$. These packages are "drop-in" replacements for standard 4-pin CMOS quartz crystal oscillators.

Package Types



Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Supply Voltage	
ESD Protection	4000V HBM, 400V MM, 2000V CDM

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V_{DD} = 1.8V –5% to 3.3V +10%, T_A = –40°C to 85°C.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Supply Voltage Note 1	V_{DD}	1.71	-	3.63	V	_	
Active Supply Current	I _{DD}	_	1.3	_	mA	F _{OUT} = 24 MHz, V _{DD} = 1.8V, No Load	
Standby Supply Current	la	_	12	_	_	V _{DD} = 1.8/2.5V	
Note 2	I _{STBY}	_	80	_	μΑ	V _{DD} = 3.3V	
Frequency Stability Note 3	Δf	_	_	±25 ±50	ppm	All temp ranges	
A min m	A.f.	_	_	±5		1st year @25°C	
Aging	Δf	_	_	±1	ppm	Per year after first year	
Startup Time	t _{SU}	_	_	1.3	ms	From 90% V _{DD} to valid clock output, T = 25°C	
Input Logic Levels Note 4	V_{IH}	0.7xV _{DD}	-	_	V		
Input Logic High Input Logic Low	V_{IL}	_		0.3xV _{DD}	V	_	
Output Disable Time Note 5	t _{DA}	_	1	200+Period	μS	_	
Output Enable Time Note 6	$t_{\sf EN}$	_	-	1	μS	_	
Enable Pull-up Resistor Note 7	_	_	300	_	kΩ	If configured	
Output Logic Levels	V_{OH}	0.8xV _{DD}	_	_	V	I = 1mA	
Output Logic High Output Logic Low	V_{OL}	_	_	0.2xV _{DD}	V	I = -1mA	

- Note 1: Pin 4 V_{DD} should be filtered with 0.1 uf capacitor.
 - 2: Not including current through pull-up resistor on EN pin (if configured). Higher standby current seen at >3.3V V_{DD}.
 - 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
 - 4: Input waveform must be monotonic with rise/fall time < 10 ms
 - **5:** Output Disable time takes up to 1 Period of the output waveform + 200 ns.
 - **6:** For parts configured with OE, not Standby.
 - 7: Output is enabled if pad is floated or not connected.
 - 8: Output Duty Cycle will be 40% to 60% when output frequency is between 40 MHz to 60 MHz.

DSC60XX

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, V _{DD} = 1.8V –5% to 3.3V +10%, T _A = –40°C to 85°C.								
Parameters	Sym.	Min.	Тур.	Max.	Units	Cond	ditions	
	. /.	_	2.5	3.5		DSC60x3 Low Drive, 20% to 80% C _L =5 pF	V _{DD} = 1.8V	
Output Transition Time	t _{RX} /t _{FX}	_	1.5	2.2	ns		V _{DD} = 2.5V/3.3V	
Rise Time/Fall Time	+ /+	_	1.2	2.0		DSC60x1 Std. Drive,	V _{DD} = 1.8V	
	t _{RY} /t _{FY}	_	0.6	1.2	ns	20% to 80% C _L =10 pF	V _{DD} = 2.5V/3.3V	
Frequency	f_0	0.002	_	80	MHz	Output on Pir	1 for < 1 MHz	
Output Duty Cycle, Note 8	SYM	45	_	55	%			
	J _{PER}	_	32	40		DSC60x3 Low Drive, FOUT = 27 MHz DSC60x1 Std. Drive, FOUT = 27 MHz	V _{DD} = 1.8V	
		_	25	32			V _{DD} = 2.5V/3.3V	
Period Jitter, RMS		_	23	30	ps _{RMS}		V _{DD} = 1.8V	
		_	20	28			V _{DD} = 2.5V/3.3V	
		_	180	240		DSC60x3 Low Drive,	V = 4.9V	
Cycle-to-Cycle Jitter		_	120	170		F _{OUT} = 27 MHz	V _{DD} = 1.8V	
(peak)	J _{Cy-Cy}	_	115	190	μs	DSC60x1, Std. Drive, F _{OUT} = 27 MHz	V _{DD} =	
		_	90	150			2.5V/3.3V	

- **Note 1:** Pin 4 V_{DD} should be filtered with 0.1 uf capacitor.
 - 2: Not including current through pull-up resistor on EN pin (if configured). Higher standby current seen at $>3.3 \text{V}_{DD}$.
 - 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
 - 4: Input waveform must be monotonic with rise/fall time < 10 ms
 - 5: Output Disable time takes up to 1 Period of the output waveform + 200 ns.
 - **6:** For parts configured with OE, not Standby.
 - 7: Output is enabled if pad is floated or not connected.
 - 8: Output Duty Cycle will be 40% to 60% when output frequency is between 40 MHz to 60 MHz.

TEMPERATURE SPECIFICATIONS

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature	T _J	_	+150	_	°C	_
Storage Temperature Range	T _A	-55	_	+150	°C	_
Soldering Temperature	T _S	_	+260	_	°C	40 Sec. Max.

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: DSC6001/03/11/13/21/23/41/43/51/53/61/63 PIN FUNCTION TABLE (OUTPUT ≥1 MHZ)

Pin Number	Pin Name	Pin Type	Description
	OE		Output Enable: H = Specified Frequency Output, Note 1 L = Output is high impedance
1	STBY	I	Standby: H = Specified Frequency Output, Note 1 L = Output is high impedance, Device is in low power mode, Supply current is at I _{STBY}
	FS		Frequency Select: H = Output Frequency 1, Note 2 L = Output Frequency 2
2	GND	Power	Power supply ground
3	Output	0	Oscillator clock output
4	VDD	Power	Power supply, Note 3

- Note 1: DSC600x/1x/2x has 300 kΩ internal pull-up resistor on pin1. DSC604x/5x/6x has no internal pull-up resistor on pin1 and needs external pull up or being driven by other chip.
 - 2: Two pre-programmed frequencies can be configured at http://clockworks.microchip.com/timing/.
 - 3: Bypass with 0.1 µF capacitor placed as close to VDD pin as possible.

TABLE 2-2: DSC6083 PIN FUNCTION TABLE (OUTPUT FREQUENCY < 1 MHZ)

Pin Number	Pin Name	Pin Type	Description
1	Output	0	Oscillator clock output
2	GND	Power	Power supply ground
3	DNC	DNC	Do Not Connect
4	VDD	Power	Power supply, Note 1

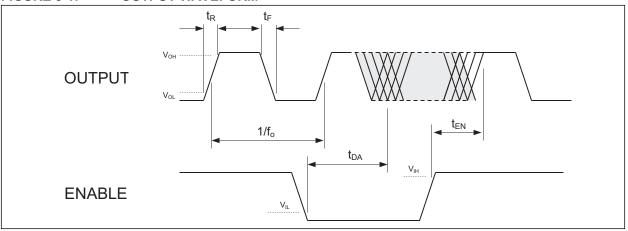
Note 1: Bypass with 0.1 μF capacitor placed as close to V_{DD} pin as possible.

DSC60xx family is available in multiple output driver configurations.

The low-drive DSC60x3 is configured with a low-power driver minimizing current consumption and EMI while delivering greater than 1 mA output current at 20%/80% of the supply voltage. The standard-drive DSC60x1 delivers greater than 3 mA output current at 20%/80% of the supply voltage.

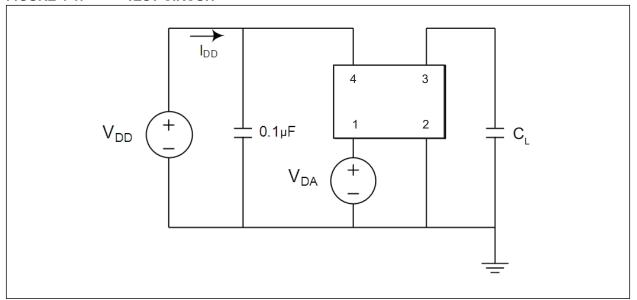
3.0 OUTPUT WAVEFORM

FIGURE 3-1: OUTPUT WAVEFORM



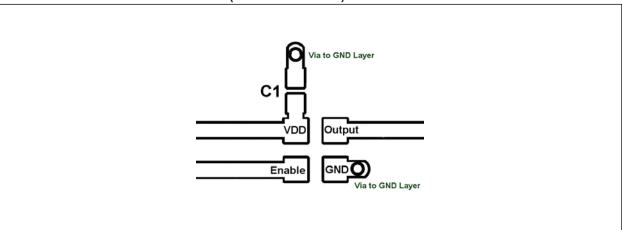
4.0 TEST CIRCUIT

FIGURE 4-1: TEST CIRCUIT



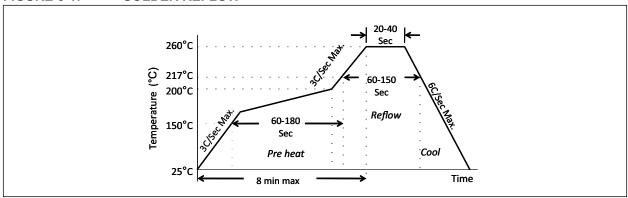
5.0 BOARD LAYOUT (RECOMMENDED)

FIGURE 5-1: BOARD LAYOUT (RECOMMENDED)



6.0 SOLDER REFLOW PROFILE

FIGURE 6-1: SOLDER REFLOW



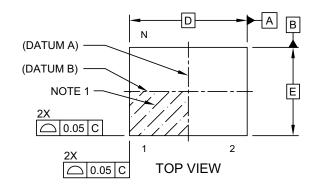
MSL 1 @ 260°C refer to JSTD-020C						
Ramp-Up Rate (200°C to Peak Temp)	3°C/Sec Max.					
Preheat Time 150°C to 200°C	60-180 Sec					
Time maintained above 217°C	60-150 Sec					
Peak Temperature	255-260°C					
Time within 5°C of actual Peak	20-40 Sec					
Ramp-Down Rate	6°C/Sec Max.					
Time 25°C to Peak Temperature	8 min. Max.					

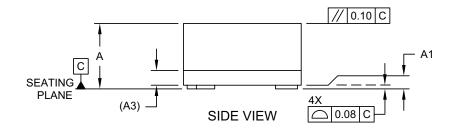
7.0 PACKAGING INFORMATION

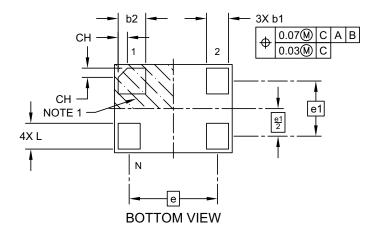
4-Lead VFLGA 1.6 mm x 1.2 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





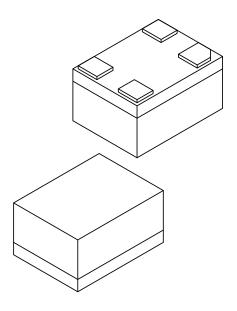


Microchip Technology Drawing C04-1199A Sheet 1 of 2

4-Lead VFLGA 1.6 mm x 1.2 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Number of Terminals	N		4	
Terminal Pitch	е		1.20 BSC	
Terminal Pitch	e1		0.75 BSC	
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D		1.60 BSC	
Overall Width	Е		1.20 BSC	
Terminal Width	b1	0.25	0.30	0.35
Terminal Width	b2	0.325	0.375	0.425
Terminal Length	L	0.30	0.35	0.40
Terminal 1 Index Chamfer	CH	-	0.125	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

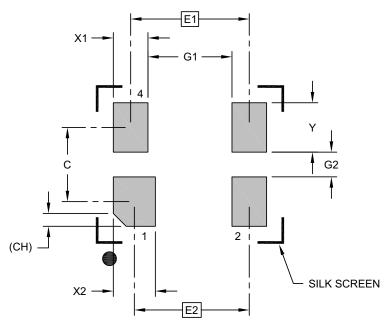
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1199A Sheet 2 of 2

4-Lead VFLGA 1.6 mm x 1.2 mm Recommended Land Pattern

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E1		1.20 BSC	
Contact Pitch	E2		1.16 BSC	
Contact Spacing	С		0.75	
Contact Width (X3)	X1			0.35
Contact Width	X2			0.43
Contact Pad Length (X6)	Υ			0.50
Space Between Contacts (X4)	G1	0.85		
Space Between Contacts (X3)	G2	0.25		
Contact 1 Index Chamfer	СН	0.13 X 45° REF		

Notes:

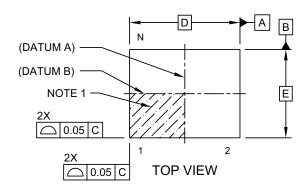
Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

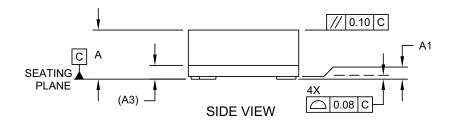
Microchip Technology Drawing C04-3199A

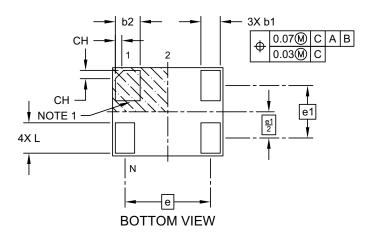
4-Lead VLGA 2.0 mm x 1.6 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





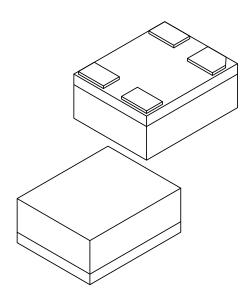


Microchip Technology Drawing C04-1200A Sheet 1 of 2

4-Lead VLGA 2.0 mm x 1.6 mm Package Outline (Continued)

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Number of Terminals	Ν		6	
Terminal Pitch	е		1.55 BSC	
Terminal Pitch	e1		0.95 BSC	
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D		2.00 BSC	
Overall Width	E		1.60 BSC	
Terminal Width	b1	0.30	0.35	0.40
Terminal Width	b2	0.40	0.45	0.50
Terminal Length	Ĺ	0.50	0.55	0.60
Terminal 1 Index Chamfer	СН	-	0.15	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M $\,$

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

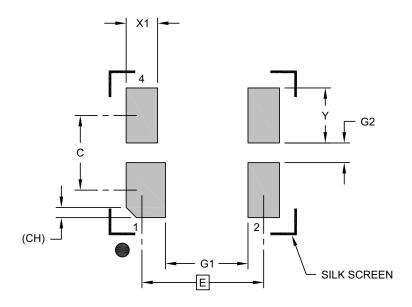
 $\label{eq:REF:Reference Dimension, usually without tolerance, for information purposes only. \\$

Microchip Technology Drawing C04-1200A Sheet 2 of 2

4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е	1.55 BSC		
Contact Spacing	С		0.95	
Contact Width (X4)	X1			0.50
Contact Width (X2)	X2			0.40
Contact Pad Length (X6)	Υ			0.70
Space Between Contacts (X4)	G1	1.05		
Space Between Contacts (X3)	G2	0.25		
Contact 1 Index Chamfer	CH	0.13 X 45° REF		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

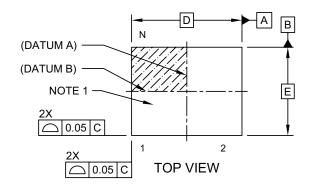
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

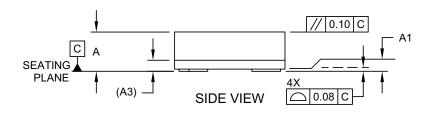
Microchip Technology Drawing C04-3200A

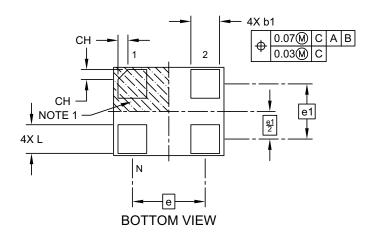
4-Lead VLGA 2.5 mm x 2.0 mm Package Outline

4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





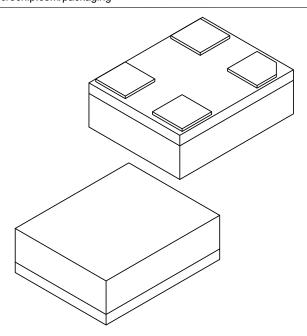


Microchip Technology Drawing C04-1202A Sheet 1 of 2

4-Lead VLGA 2.5 mm x 2.0 mm Package Outline (Continued)

4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Number of Terminals	N		4	
Terminal Pitch	е		1.65 BSC	
Terminal Pitch	e1		1.25 BSC	
Overall Height	Α	0.79 0.84 0.8		
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3		0.20 REF	
Overall Length	D		2.50 BSC	
Overall Width	Е	2.00 BSC		
Terminal Width	b1	0.60	0.65	0.70
Terminal Length	Ĺ	0.60	0.65	0.70
Terminal 1 Index Chamfer	СН	-	0.225	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

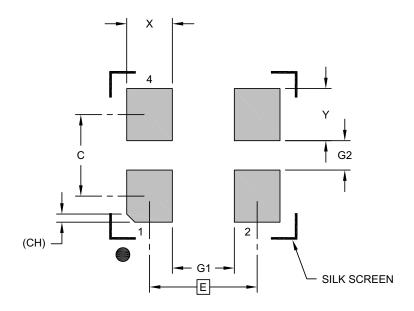
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1202A Sheet 2 of 2

4-Lead VLGA 2.5 mm x 2.0 mm Recommended Land Pattern

4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	MILLIMETERS			
Dimension	MIN	NOM	MAX		
Contact Pitch	Е	1.65 BSC			
Contact Spacing	С		1.25		
Contact Width (X4)	Х			0.70	
Contact Pad Length (X6)	Υ			0.80	
Space Between Contacts (X4)	G1	0.95			
Space Between Contacts (X3)	G2	0.45			
Contact 1 Index Chamfer	CH	0.13 X 45° REF			

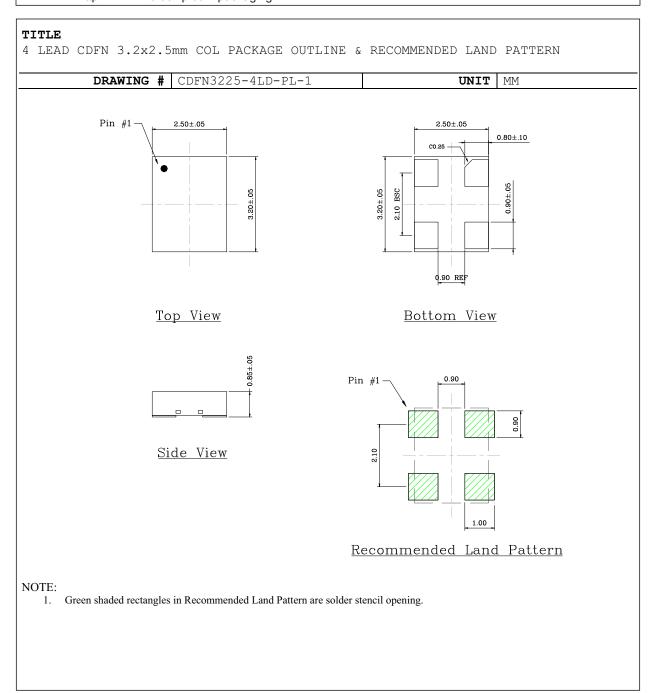
Notes:

Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3202A

4-Lead CDFN 3.2 mm x 2.5 mm Package Outline and Recommended Land Pattern

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



APPENDIX A: REVISION HISTORY

Revision A (September 2016)

• Initial creation of DSC60XX Microchip data sheet DS20005625A.



NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

						Exa	mples	s:	
PART NO. X Device Pin 1 Ou Definition Dr Stre	X X tput Package ive ength	X Temperature Range	X 2 Frequency Revi	X – XXX.XXXX sion Frequenc	· T	a)	DSC	6013JI2A-024.00	00: Ultra-Low Power MEMS Oscillator, Pin1= Standby with internal Pull-Up, Low Output Drive Strength, 4-
Device:	DSC60XX:	Ultra-Lo	w Power MEMS	Oscillator					Lead 2.5 mm x2.0 mm VFLGA, Industrial Temperature (-40°C to 85°C),
Pin Definition: Output Drive Strength:	Selection 0 1 2 4 5 6 8	Pin 1 OE STDBY FS OE STDBY FS KHz Output Standard Low	Internal Pull Re Pull-up Pull-up Pull-up None None None	egister		b)		6001HE1A-016.0	±25 ppm, Revision A, 24 MHz Frequency, Bulk 1000T: Ultra—Low Power MEMS Oscillator, Pin1= OE with internal Pull—Up, Standard Output Drive Strength, 4-Lead 1.6 mm x1.2 mm VFLGA, Extended Commercial Temperature (-20°C to 70°C), ±50 ppm, Revision A, 16 MHz Frequency, Tape and Reel 768: Ultra—Low Power MEMS Oscillator, Pin1= 32.768KHz Clock Output , Low Output Drive Strength.
Packages:	C = J = M = H =	4-Lead 2.5 4-Lead 2.0 4-Lead 1.6	2 mm x 2.5 mm E 5 mm x 2.0 mm V 0 mm x 1.6 mm V 6 mm x 1.2 mm V	/FLGA /FLGA /FLGA					4-Lead 2.0 mm x1.6 mm VFLGA, Extended Commercial Temperature (–20°C to 70°C), ±50 ppm, Revision A, Bulk
Temperature Range: Frequency Stability:	E =		70°C (Extended ·85°C (Industrial)			d)	DSC	6023CI2A-001B:	Ultra-Low Power MEMS Oscillator, Pin1= FS with internal Pull-up, Low Out- put Drive Strength, 4-Lead 3.2 mm x2.5 mm CDFN, Industrial Temperature
Revision:	A =	Revision A							(-40°C to 85°C), ±25 ppm, Revision A, Frequency code = 001B (configured
Frequency:		001.0000 User-Define and 999.9 Frequency	configuration cod the part online th	0 MHz tween 002.000 de when pin 1 =	FS.	Note		catalog part numb identifier is used for	through ClockWorks), Bulk intifier only appears in the er description. This or ordering purposes and the device package. Check
Tape and Reel:	Blank = T =	Bulk Tape and I	Reel					with your Microchi	p Sales Office for package e Tape and Reel option.

Note 1: Please visit Microchip ClockWorks[®] Configurator Website to configure the part number for customized frequency. http://clockworks.microchip.com/timing/.



NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
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